Low Noise Amplifier MM-LNA-010080-30-1 1 to 8 GHz

General Description:

MM-LNA-010080-30-1 is a Low Noise Amplifier that operates over the frequency range of 1.0 to 8.0 GHz. This model provides a typical gain of 30 dB and a typical noise figure of 1.5 dB. It provides an OP1dB of 16 dB typical and operates on +15 VDC witha typical current draw of 220 mA.

Features:

• Ultra Wide Band: 1.0-8.0 GHz

• Gain: 30 dB

50 Ohm input and output match

Internally regulated

Unconditionally stable

Applications:

- Radar Systems
- Communication Systems
- Receivers Systems

Electrical Specifications (23° C):

Dovomotov	Value			Haita
Parameter	Min	Тур	Max	Units
Frequency Range	1		8	GHz
Gain	20	30		dB
Gain Flatness		±1.5	±2.0	dB
Noise Figure		1.5	2.0	dB
Output Power (P1dB)	15	16		dBm
Output IP3		26		dBm
Input VSWR		1.8	2.0	:1
Output VSWR		1.8	2.0	:1
DC Voltage		+15		V
DC Current		220		mA

Absolute Maximum Ratings:

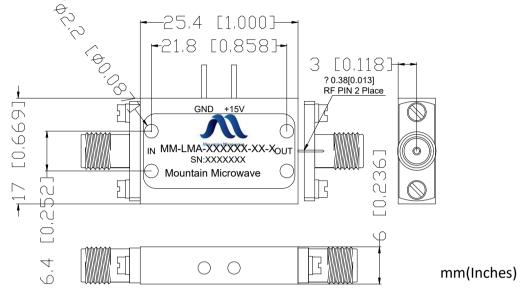
Condition	Value	
DC Voltage	+18V	
Maximum Input Power(CW)	-10 dBm	
ESD sensitivity (HBm)	Class 0, passed 150V	

Mechanical Specifications:

Parameter	Value	
Length	25.4 mm	
Width	17 mm	
Height	6 mm	
RF Connector	SMA Female	

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Outline Drawing:



Environmental Conditions:

Parameter	Standard	Description	
Operational Temperature		-45°C~+85°C	
Storage Temperature		-55°C~+125°C	
Random Vibration	MIL-STD-883K, Method 2026, Cond. IB	50 - 2000 Hz, 7.3 Grms	
Humidity	MIL-STD-202, Method 103B, Cond. B	100% RH at 35c, 95%RH at 40°C	
Altitude	MIL-STD-883K, Method 1001, Cond. C	50,000 feet	

Caution:

- Exceeding absolute maximum ratings shown will damage the device.
- The device is static sensitive. Always follow ESD rules when working with the device.
- Heat Sink required during operation.